

Standard Rectifier

$$V_{RRM} = 2 \times 1200 \text{ V}$$

$$I_{FAV} = 10 \text{ A}$$

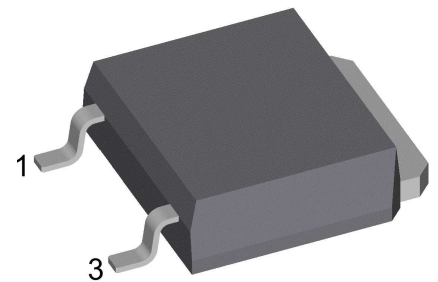
$$V_F = 1.27 \text{ V}$$

Phase leg

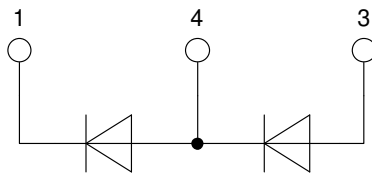
Part number

DMA10P1200UZ

Marking on Product: MATMZP



Backside: anode/cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour
- High commutation robustness
- High surge capability

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-252 (DPak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- High creepage distance between terminals

Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

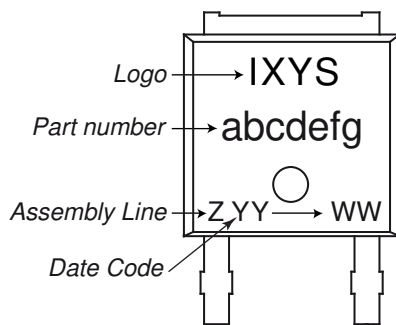
- to perform joint risk and quality assessments;

- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1300	V	
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1200	V	
I_R	reverse current	$V_R = 1200 V$	$T_{VJ} = 25^{\circ}C$		5	μA	
		$V_R = 1200 V$	$T_{VJ} = 150^{\circ}C$		0.05	mA	
V_F	forward voltage drop	$I_F = 5 A$	$T_{VJ} = 25^{\circ}C$		1.29	V	
		$I_F = 10 A$			1.55	V	
		$I_F = 5 A$	$T_{VJ} = 150^{\circ}C$		1.27	V	
		$I_F = 10 A$			1.63	V	
I_{FAV}	average forward current	$T_C = 140^{\circ}C$ 180° sine	$T_{VJ} = 175^{\circ}C$		10	A	
V_{FO}	threshold voltage	} for power loss calculation only	$T_{VJ} = 175^{\circ}C$		0.90	V	
r_F	slope resistance				37	m Ω	
R_{thJC}	thermal resistance junction to case				2	K/W	
R_{thCH}	thermal resistance case to heatsink			0.5		K/W	
P_{tot}	total power dissipation		$T_C = 25^{\circ}C$		75	W	
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}C$		100	A	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 V$		110	A	
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}C$		85	A	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 V$		92	A	
I^2t	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}C$		50	A ² s	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 V$		50	A ² s	
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}C$		36	A ² s	
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$	$V_R = 0 V$		35	A ² s	
C_J	junction capacitance	$V_R = 400 V; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		1	pF	

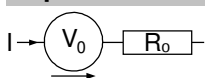
Package TO-252 (DPak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			20	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				0.3		g
F_C	mounting force with clip		20		60	N
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	3.6			mm
$d_{Spb/Apb}$		terminal to backside	3.0			mm

Product Marking

Part description

D = Diode
 M = Standard Rectifier
 A = (up to 1800V)
 10 = Current Rating [A]
 P = Phase leg
 1200 = Reverse Voltage [V]
 UZ = TO-252AA (DPak) (2HV)

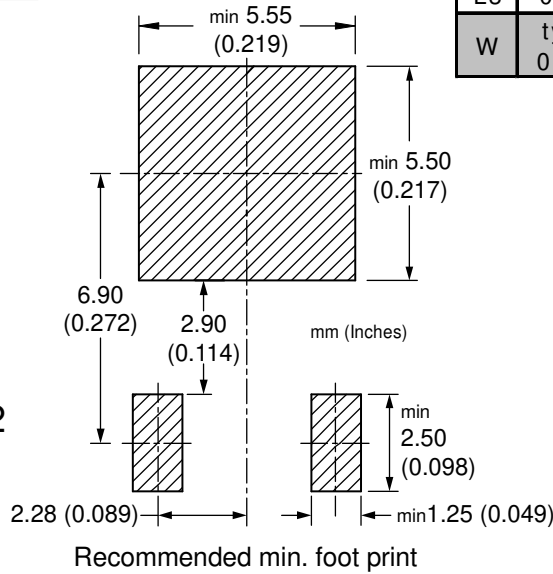
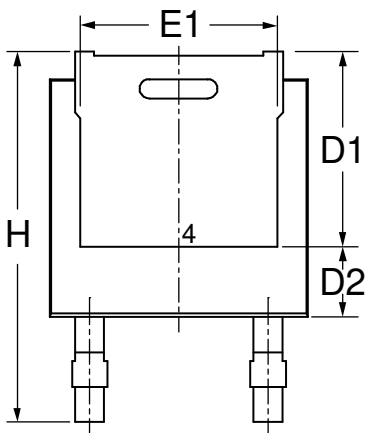
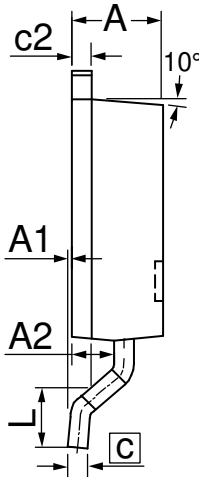
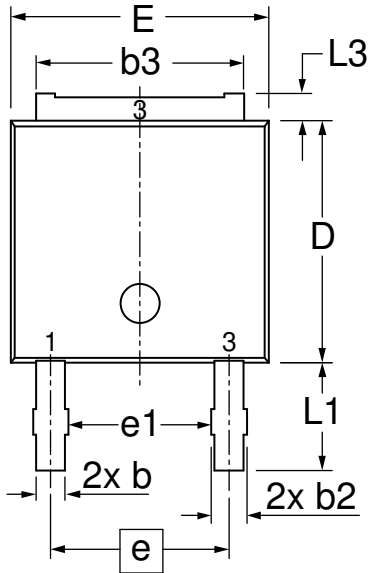
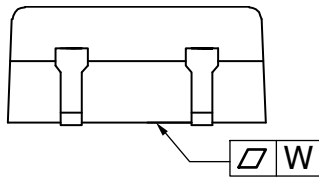
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DMA10P1200UZ-TRL	MATMZP	Tape & Reel	2500	524603
Alternative	DMA10P1200UZ-TUB	MATMZP	Tube	70	524596

Similar Part	Package	Voltage class
DMA10P1600UZ	TO-252AA (DPak) (2HV)	1600

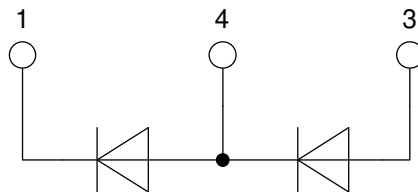
Equivalent Circuits for Simulation
** on die level*
 $T_{VJ} = 175\text{ °C}$

Rectifier

$V_{0\ max}$	threshold voltage	0.9	V
$R_{0\ max}$	slope resistance *	34	mΩ

Outlines TO-252 (DPak)



Dim	Millimeters		Inches	
	min	max	min	max
A	2.18	2.39	0.086	0.094
A1	0.00	0.13	0.000	0.005
A2	0.97	1.17	0.038	0.046
b	0.64	0.89	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	5.08	5.59	0.200	0.220
c	0.46	0.61	0.018	0.024
c2	0.46	0.58	0.018	0.023
D	5.97	6.22	0.235	0.245
D1	4.57	5.21	0.180	0.205
D2	2.03		0.080	
E	6.35	6.73	0.250	0.265
E1	4.32	5.21	0.170	0.205
e	4.57		0.180	
e1	3.62		0.143	
H	9.15	10.34	0.360	0.407
L	1.40	1.78	0.055	0.070
L1	2.54	2.92	0.100	0.115
L3	0.64	1.02	0.025	0.040
W	typ. 0.02	0.040	typ. 0.0008	0.000



Rectifier

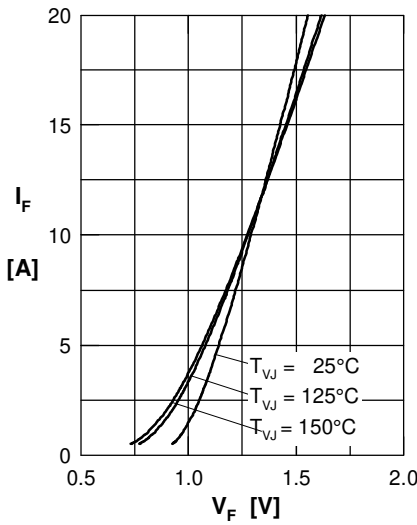


Fig. 1 Forward current versus voltage drop per diode

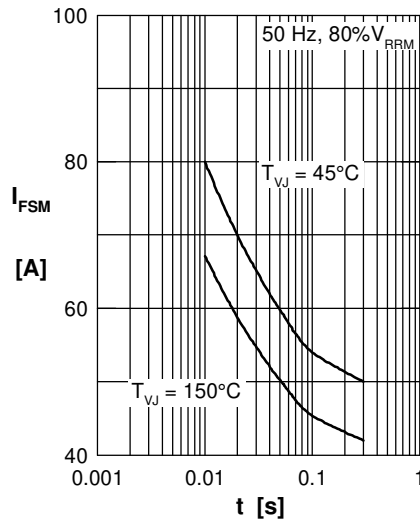


Fig. 2 Surge overload current

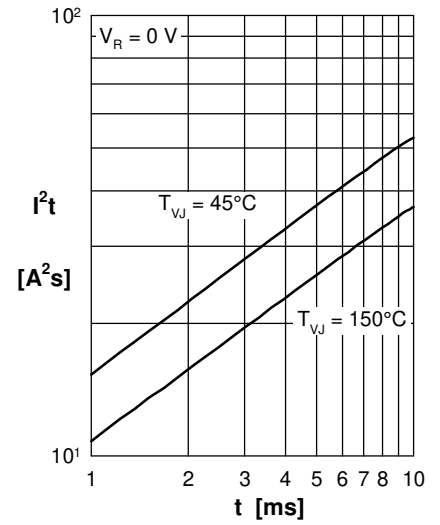


Fig. 3 I^2t versus time per diode

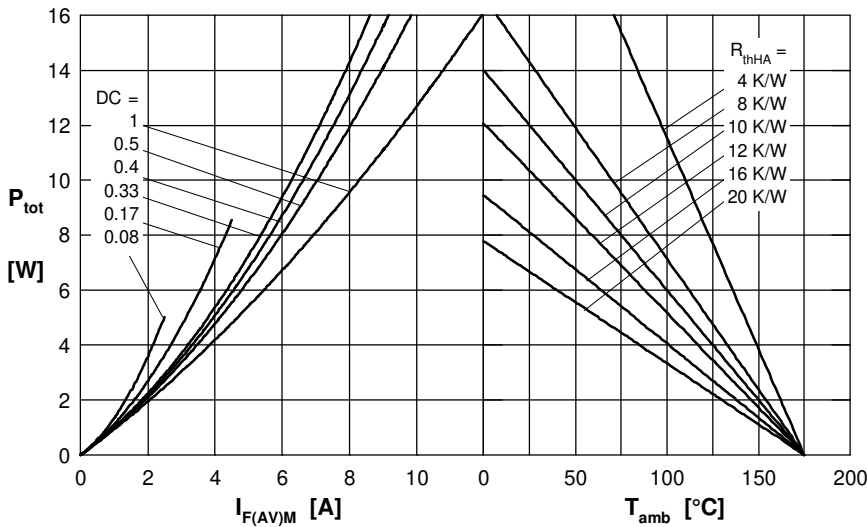


Fig. 4 Power dissipation vs. direct output current and ambient temperature

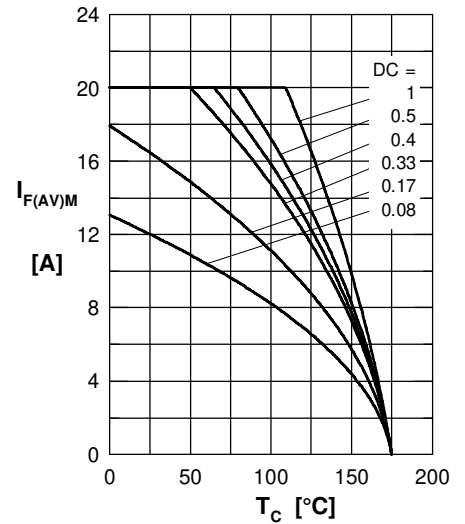


Fig. 5 Max. forward current vs. case temperature

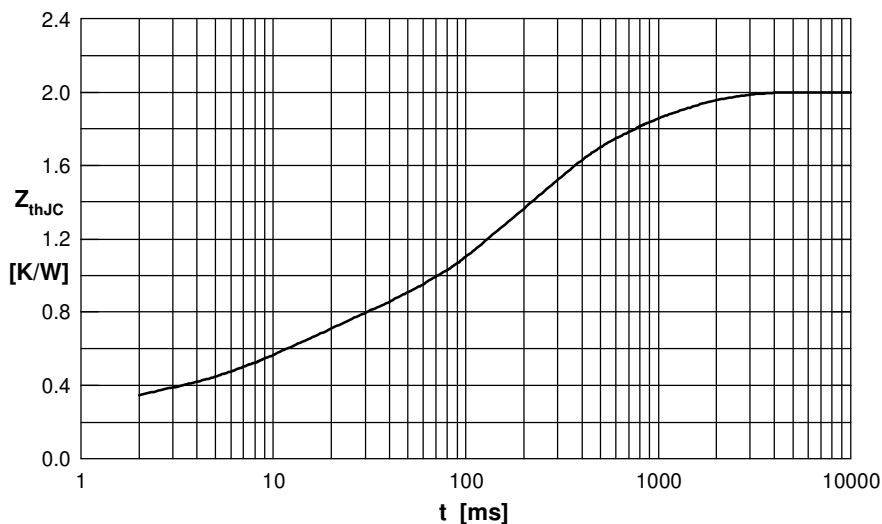


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.275	0.0005
2	0.385	0.0105
3	0.880	0.1700
4	0.460	0.8500